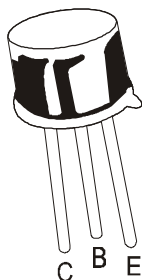


NPN SILICON PLANAR TRANSISTORS



BSX45

BSX46

BSX47

TO-39

Metal Can Package

AMPLIFIER TRANSISTORS

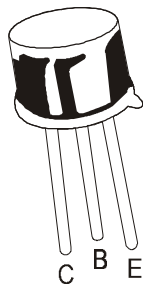
ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL		BSX45	BSX46	BSX47	UNITS
Collector Emitter Voltage	V_{CEO}		40	60	80	V
Collector Emitter Voltage	V_{CES}		80	100	120	V
Emitter Base Voltage	V_{EBO}			7.0		V
Collector Current Continuous	I_C			1.0		A
Power Dissipation @ Ta=25° C	P_D			1.0		W
Derate Above 25° C				5.71		mW/ °C
Power Dissipation@ Tc=25° C	P_D			5.0		W
Derate Above 25° C				28.6		mW/ °C
Operating And Storage Junction Temperature Range	T_j, T_{stg}			-65 to +200		°C
THERMAL RESISTANCE						
Junction to Ambient	$R_{th(j-a)}$			200		°C/W
Junction to Case	$R_{th(j-c)}$			35		°C/W

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	BSX45	BSX46	BSX47	UNITS
Collector Emitter Voltage	V_{CEO}^*	$I_C=30mA, I_B=0$	>40	>60	>80	V
	V_{CES}	$I_C=100\mu A, V_{BE}=0$	>80	>100	>120	V
Emitter Base Voltage	V_{EBO}	$I_E=100\mu A, I_C=0$		>7.0		V
Collector Cut off Current	I_{CES}	$V_{CE}=60V, V_{BE}=0$	<10	<10		nA
		$V_{CE}=80V, V_{BE}=0$			<10	nA
	I_{CES}	$T_c=150^\circ C$				
		$V_{CE}=60V, V_{BE}=0$	<10	<10		μA
		$V_{CE}=80V, V_{BE}=0$			<10	μA
Emitter Cut off Current	I_{EBO}	$V_{EB}=5V, I_C=0$		<10		nA

NPN SILICON PLANAR TRANSISTORS



BSX45

BSX46

BSX47

TO-39

Metal Can Package

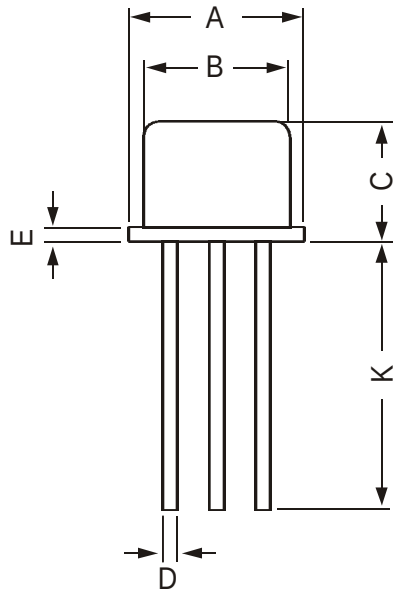
ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNITS
DC Current Gain	h_{FE}	$I_C=0.1mA, V_{CE}=1V$		
		Group -6	>10	
		Group -10	>15	
		Group -16	>25	
	h_{FE}	$I_C=100mA, V_{CE}=1V^*$		
		Group -6	40 to 100	
		Group -10	63 to 160	
		Group -16	100 to 250	
	h_{FE}	$I_C=500mA, V_{CE}=1V^*$		
		Group -6	>15	
		Group -10	>25	
		Group -16	>35	
Base Emitter on Voltage	$V_{BE(on)}^*$	$I_C=100mA, V_{CE}=1V$	<1.0	V
		$I_C=500mA, V_{CE}=1V$	0.75 to 1.5	V
		$I_C=1A, V_{CE}=1V$	<2.0	V
Collector Emitter Saturation Voltage	$V_{CE(sat)}^*$	$I_C=1A, I_B=0.1A$	<1.0	V
<u>DYNAMIC CHARACTERISTICS</u>				
Transition Frequency	f_T	$I_C=50mA, V_{CE}=10V$ $f=20MHz$	>50	MHz
Emitter Base Capacitance	C_{ib}	$V_{BE}=0.5V, f=1MHz$	<80	pF
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		
BSX45			<25	pF
BSX46			<20	pF
BSX47			<15	pF
Turn on time	t_{on}	$I_C=100mA, I_{B1}=-I_{B2}=$	<200	ns
Turn off time	t_{off}	5mA	<850	ns

*Pulse Test: Pulse Duration =300ms, Duty Cycle =1%

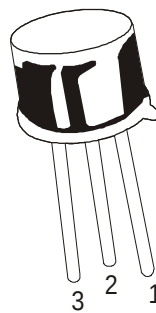
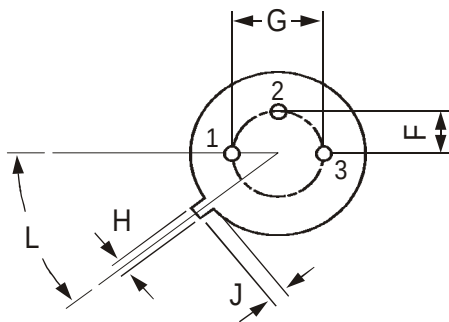
BSX45
BSX46
BSX47

TO-39 Metal Can Package



All dimensions are in mm

DIM	MIN	MAX
A	8.50	9.39
B	7.74	8.50
C	6.09	6.60
D	0.40	0.53
E	—	0.88
F	2.41	2.66
G	4.82	5.33
H	0.71	0.86
J	0.73	1.02
K	12.70	—
L	42 DEG	48 DEG



PIN CONFIGURATION
 1. EMITTER
 2. BASE
 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Disclaimer

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